



Vishay General Semiconductor

# Surface Mount TRANSZORB® Transient Voltage Suppressors



DO-214AB (SMC)

### **MAJOR RATINGS AND CHARACTERISTICS**

V <sub>(BR)</sub>	6.8 V to 220 V		
P <sub>PPM</sub>	1500 W		
PD	6.5 W		
I <sub>FSM</sub> (Unidirectional only)	200 A		
T <sub>j</sub> max.	150 °C		

### **MECHANICAL DATA**

Case: DO-214AB (SMC)

Epoxy meets UL 94V-0 flammability rating

**Terminals:** Matte tin plated leads, solderable per J-STD-002B and JESD22-B102D

E3 suffix for commercial grade, HE3 suffix for high reliability grade (AEC Q101 qualified)

**Polarity:** For unidirectional types the band denotes cathode end, no marking on bidirectional types

### **DEVICES FOR BIDIRECTION APPLICATIONS**

For bidirectional devices use CA suffix (e.g. SM15T12CA). Electrical characteristics apply in both directions.

### FEATURES

- · Low profile package
- · Ideal for automated placement
- · Glass passivated chip junction
- 1500 W peak pulse power capability with a 10/1000 μs waveform
- Available in Unidirectional and Bidirectional
- Excellent clamping capability
- · Low inductance
- Meets MSL level 1, per J-STD-020C, LF max peak of 260 °C
- Solder Dip 260 °C, 40 seconds
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

### **APPLICATION NOTES**

A 1500 W (SMC) device is normally selected when the threat of transients is from lightning induced transients, conducted via external leads or I/O lines. It is also used to protect against switching transients induced by large coils or industrial motors. Source impedance at component level in a system is usually high enough to limit the current within the peak pulse current (I<sub>PP</sub>) rating of this series. In an overstress condition, the failure mode is a short circuit.

### **TYPICAL APPLICATIONS**

Use in sensitive electronics protection against voltage transients induced by inductive load switching and lighting on ICs, MOSFET, signal lines of sensor units for consumer, computer, industrial, automotive and telecommunication.

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	LIMIT	UNIT				
Peak pulse power dissipation with a 10/1000 $\mu s$ waveform $^{(1,2)}$ (see Fig. 1)	P <sub>PPM</sub>	Minimum 1500	W				
Peak power pulse current with a 10/1000 $\mu$ s waveform <sup>(1)</sup> (see Fig. 3)	I <sub>PPM</sub>	see next table	А				
Power dissipation on infinite heatsink $T_A = 50$ °C	PD	6.5	W				
Peak forward surge current 10 ms single half sine-wave uni-directional only $^{\rm (2)}$	I <sub>FSM</sub>	200	А				
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	- 65 to + 150	°C				

#### Note:

(1) Non-repetitive current pulse, per Fig. 3 and derated above  $T_A = 25 \text{ }^\circ\text{C}$  per Fig. 2

(2) Mounted on 0.31 x 0.31" (8.0 x 8.0 mm) copper pads to each terminal



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ELECTRICAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)												
TYPE <sup>(1)</sup>	DEVICE MARKING CODE		STAND- OFF VOLTAGE V <sub>RM</sub> (V)	LEAKAGE CURRENT <sup>(3)</sup> I <sub>RM</sub> AT V <sub>R</sub>	BREAKDOWN VOLTAGE V <sub>(BR)</sub> AT I <sub>T</sub> <sup>(2)</sup> (V)		TEST CURRENT I <sub>T</sub> (mA)	CLAMPING VOLTAGE V <sub>C</sub> AT I <sub>PP</sub> (10/1000 µs)		CLAMPING VOLTAGE V <sub>C</sub> AT I <sub>PP</sub> (8/20 µs)		α <sub>T</sub> Max 10 <sup>-4</sup> /°C
	UNI	BI	* RM (*7		MIN	MAX	(IIIA)	(V)	(A)	(V)	(A)	
SM15T6V8A	GDE7	GDE7	5.80	1000	6.45	7.14	10	10.5	143	13.4	746	5.7
SM15T7V5A	GDK7	BDK7	6.40	500	7.13	7.88	10	11.3	132	14.5	690	6.1
SM15T10A	GDT7	BDT7	8.55	10.0	9.50	10.5	1.0	14.5	103	18.6	538	7.3
SM15T12A	GDX7	BDX7	10.2	5.0	11.4	12.6	1.0	16.7	90.0	21.7	461	7.8
SM15T15A	GEG7	GEG7	12.8	1.0	14.3	15.8	1.0	21.2	71.0	27.2	368	8.4
SM15T18A	GEM7	BEM7	15.3	1.0	17.1	18.9	1.0	25.2	59.5	32.5	308	8.8
SM15T22A	GET7	BET7	18.8	1.0	20.9	23.1	1.0	30.6	49.0	39.3	254	9.2
SM15T24A	GEV7	GEV7	20.5	1.0	22.8	25.2	1.0	33.2	45.0	42.8	234	9.4
SM15T27A	GEX7	BEX7	23.1	1.0	25.7	28.4	1.0	37.5	40.0	48.3	207	9.6
SM15T30A	GFE7	BFE7	25.6	1.0	28.5	31.5	1.0	41.5	36.0	53.5	187	9.7
SM15T33A	GFG7	GFG7	28.2	1.0	31.4	34.7	1.0	45.7	33.0	59.0	169	9.8
SM15T36A	GFK7	BFK7	30.8	1.0	34.2	37.8	1.0	49.9	30.0	64.3	156	9.9
SM15T39A	GFM7	BFM7	33.3	1.0	37.1	41.0	1.0	53.9	28.0	69.7	143	10.0
SM15T68A	GGG7	GGG7	58.1	1.0	64.6	71.4	1.0	92.0	16.3	121	83	10.4
SM15T100A	GGV7	GGV7	85.5	1.0	95.0	105	1.0	137	11.0	178	56	10.6
SM15T150A	GHK7	GHK7	128	1.0	143	158	1.0	207	7.20	265	38	10.8
SM15T200A	GHR7	GHR7	171	1.0	190	210	1.0	274	5.50	353	28	10.8
SM15T220A	GHR8	GHR8	188	1.0	209	231	1.0	328	4.60	388	26	10.8

Note:

(1) For bi-directional devices add suffix "CA" instead of "A"

(2)  $V_{BR}$  measured after  $I_T$  applied for 300  $\mu s$  square wave pulse

(3) For bipolar devices with  $V_{R}$  = 10 Volts or under, the  $I_{T}$  limit is doubled

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	VALUE	UNIT			
Typical thermal resistance junction to ambient air <sup>(1)</sup>	$R_{ extsf{ heta}JA}$	75	°C/W			
Typical thermal resistance junction to leads	$R_{ extsf{ heta}JL}$	15	°C/W			

Note:

(1) Mounted on minimum recommended pad layout

ORDERING INFORMATION								
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE				
SM15T10A-E3/57T	0.211	57T	850	7" Diameter Plastic Tape & Reel				
SM15T10A-E3/9AT	0.211	9AT	3500	13" Diameter Plastic Tape & Reel				



## **SM15T Series**

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### **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

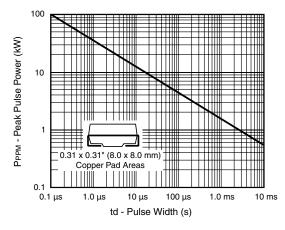


Figure 1. Peak Pulse Power Rating Curve

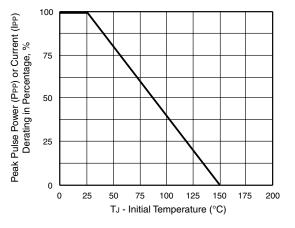


Figure 2. Pulse Power or Current versus Initial Junction Temperature

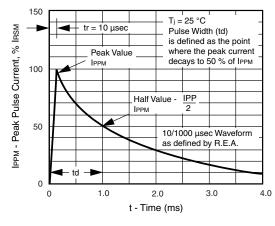


Figure 3. Pulse Waveform

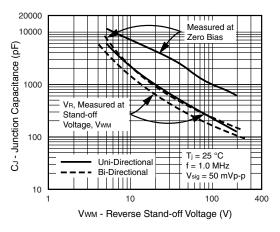


Figure 4. Typical Junction Capacitance Uni-Directional

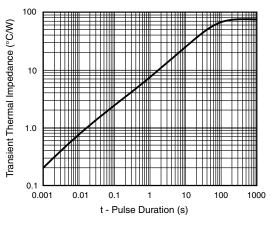


Figure 5. Typical Transient Thermal Impedance

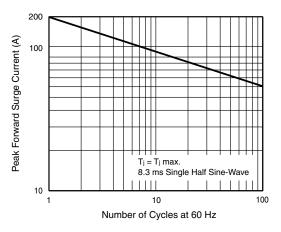
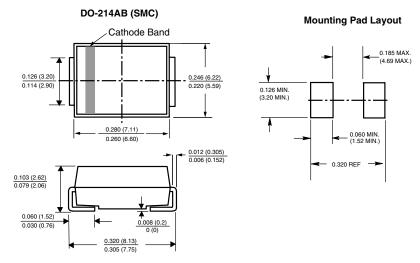


Figure 6. Maximum Non-Repetitive Forward Surge Current Uni-Directional Use Only

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### PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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